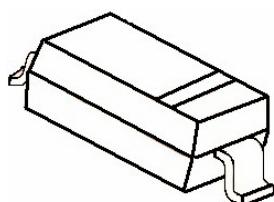


**SOD-123**

MARKING: T4

**Features**

- Fast Switching Device (TRR <4.0 nS)
- Power Dissipation of 500mW
- High Stability and High Reliability
- Low reverse leakage

**Mechanical Data**

- SOD-123 Small Outline Plastic Package
- Polarity: Color band denotes cathode end
- Epoxy UL: 94V-0
- Mounting Position: Any

**Maximum Ratings & Thermal Characteristics**

(Ratings at 25°C ambient temperature unless otherwise specified.)

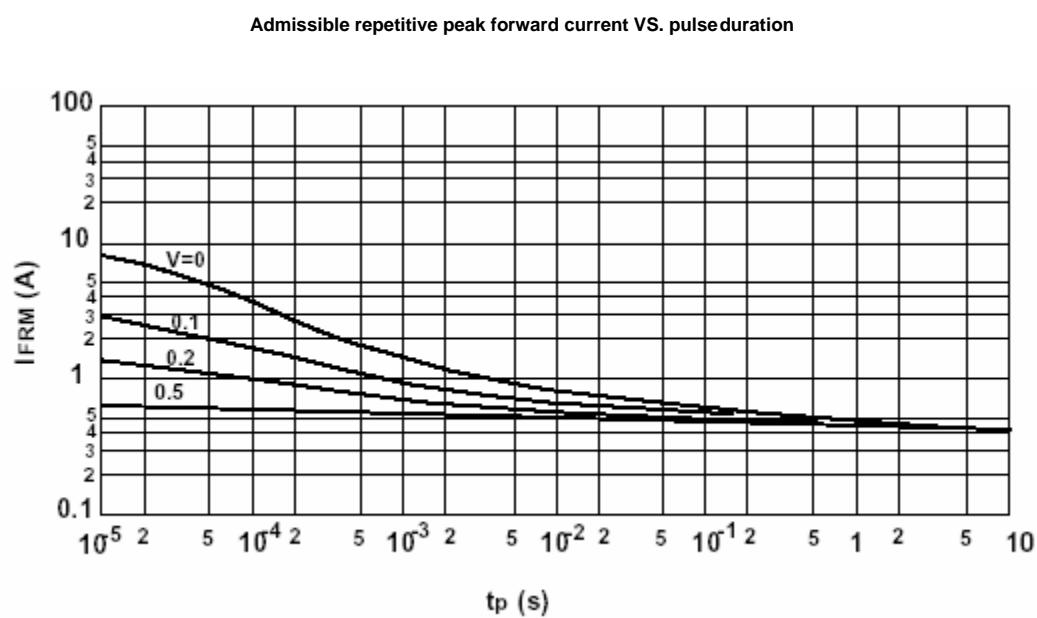
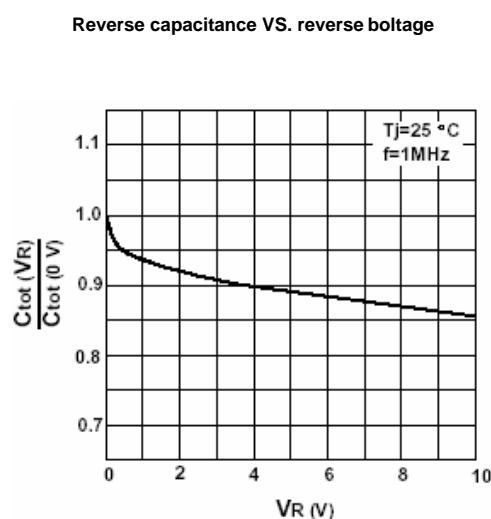
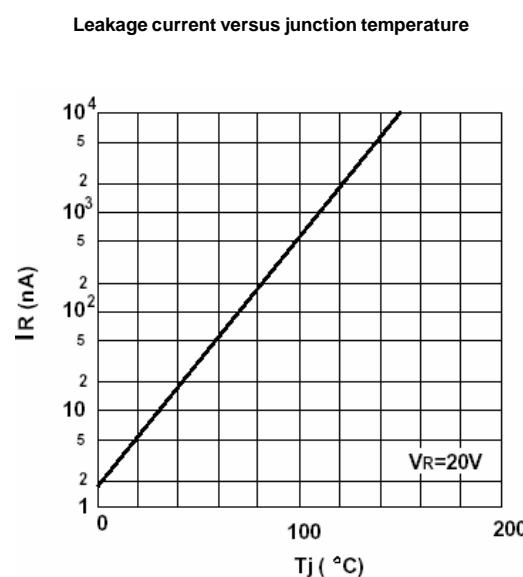
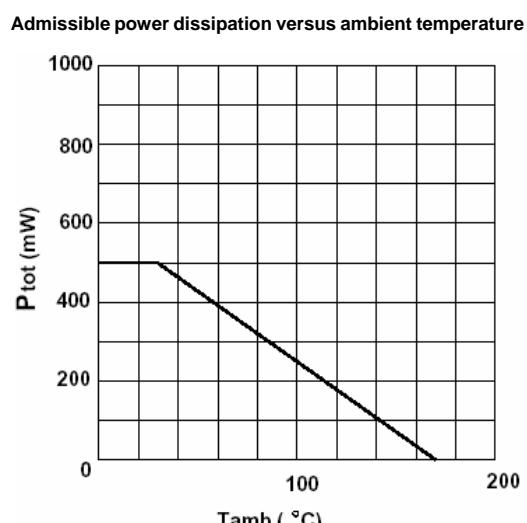
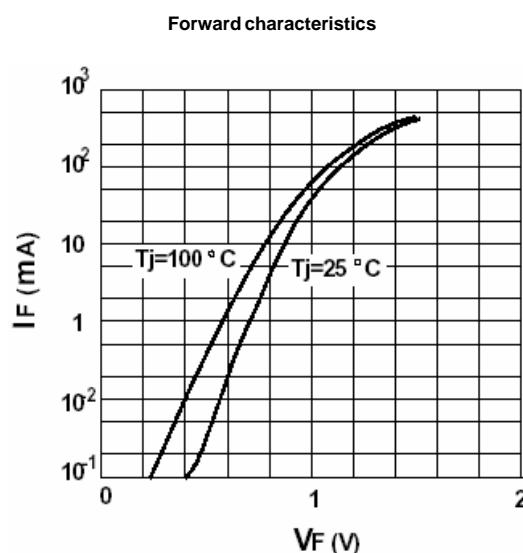
Parameters	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	75	V
Peak Reverse Voltage	V <sub>RM</sub>	100	V
Power Dissipation	P <sub>d</sub>	500	mW
Operating junction temperature	T <sub>j</sub>	150	°C
Storage temperature range	T <sub>STG</sub>	-65~+150	°C
Thermal Resistance from Junction to Ambient	R <sub>θ JA</sub>	250	°C/W
Average Rectified Current	I <sub>o</sub>	150	mA
Non-repetitive Peak Forward Current	I <sub>FM</sub>	300	mA
Peak Forward Surge Current @tp=1us; TA=25°C	I <sub>FSM</sub>	2.0	A

Valid provided that electrodes are kept at ambient temperature.

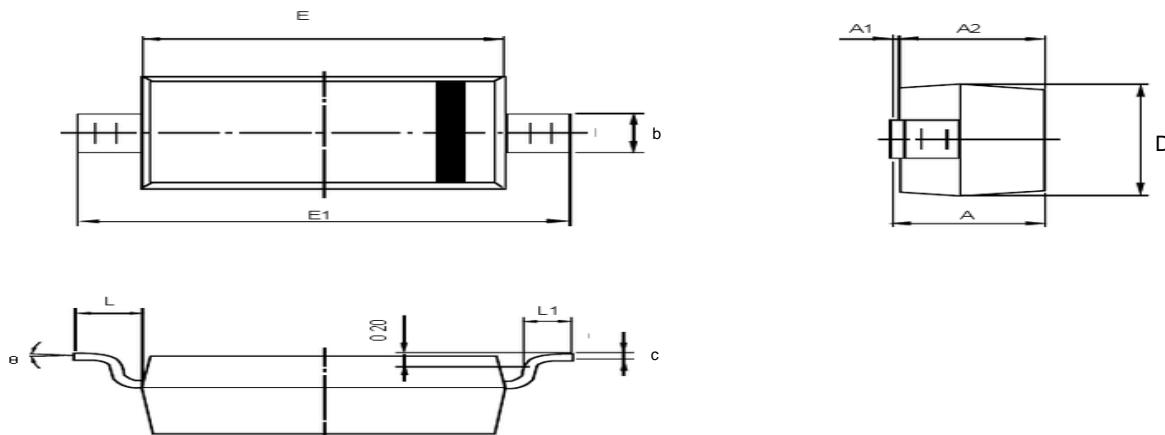
**Electrical Characteristics**

(Ratings at 25°C ambient temperature unless otherwise specified).

Symbols	Parameter	Test Condition	Limits		Unit
			Min	Max	
B <sub>v</sub>	Breakdown Voltage	IR=100uA	100		V
		IR=5uA	75		
I <sub>R</sub>	Reverse Leakage Current	VR=20V	---	25	nA
		VR=75	---	5	uA
V <sub>F</sub>	Forward Voltage	IF=10mA	---	1.00	V
		IF=100mA	---	1.25	
T <sub>RR</sub>	Reverse Recovery Time	IF = IR = 10mA, Irr=0.1XIR			nS
		RL=100Ω	---	4	
		VR=0V, f=1MHZ	---	4	
C	Capacitance				pF



## SOD-123 PACKAGE OUTLINE



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.450	0.650	0.018	0.026
c	0.080	0.150	0.003	0.006
D	1.500	1.700	0.059	0.067
E	2.600	2.800	0.102	0.110
E1	3.550	3.850	0.140	0.152
L	0.500REF		0.020REF	
L1	0.250	0.450	0.010	0.018
θ	0°	8°	0°	8°